

# International **IR** Rectifier

SCHOTTKY RECTIFIER

11DQ09  
11DQ10

1.1 Amp

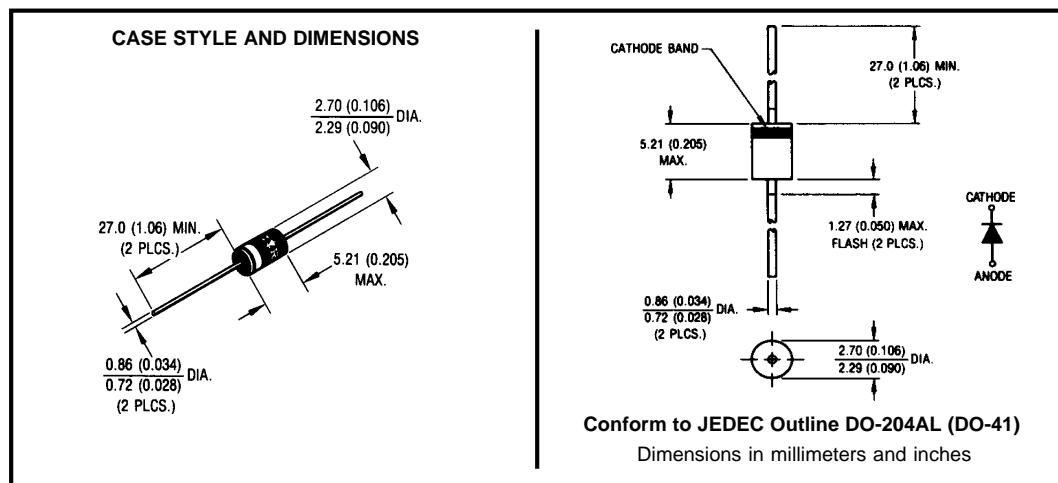
**Major Ratings and Characteristics**

Characteristics	11DQ..	Units
$I_{F(AV)}$ Rectangular waveform	1.1	A
$V_{RRM}$	90 / 100	V
$I_{FSM}$ @ $t_p = 5 \mu s$ sine	85	A
$V_F$ @ 1 Apk, $T_J = 25^\circ C$	0.85	V
$T_J$ range	-40 to 150	°C

**Description/ Features**

The 11DQ.. axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



**Voltage Ratings**

Part number	11DQ09	11DQ10
$V_R$ Max. DC Reverse Voltage (V)	90	100
$V_{RWM}$ Max. Working Peak Reverse Voltage (V)		

**Absolute Maximum Ratings**

Parameters	11DQ..	Units	Conditions		
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 4	1.1	A	50% duty cycle @ $T_J = 75^\circ\text{C}$ , rectangular wave form		
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	85	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	
	14		10ms Sine or 6ms Rect. pulse		
$E_{AS}$ Non-Repetitive Avalanche Energy	1.0	mJ	$T_J = 25^\circ\text{C}$ , $I_{AS} = 0.5$ Amps, $L = 8$ mH		
$I_{AR}$ Repetitive Avalanche Current	0.5	A	Current decaying linearly to zero in 1 μsec Frequency limited by $T_J$ max. $V_A = 1.5 \times V_R$ typical		

**Electrical Specifications**

Parameters	11DQ..	Units	Conditions		
$V_{FM}$ Max. Forward Voltage Drop * See Fig. 1 (1)	0.85	V	@ 1A	$T_J = 25^\circ\text{C}$	
	0.96	V	@ 2A		
	0.68	V	@ 1A		
	0.78	V	@ 2A	$T_J = 125^\circ\text{C}$	
$I_{RM}$ Max. Reverse Leakage Current * See Fig. 2 (1)	0.5	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$	
	1.0	mA	$T_J = 125^\circ\text{C}$		
$C_T$ Typical Junction Capacitance	35	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) $25^\circ\text{C}$		
$L_S$ Typical Series Inductance	8.0	nH	Measured lead to lead 5mm from package body		
$dv/dt$ Max. Voltage Rate of Change	10000	V/μs	(Rated $V_R$ )		

(1) Pulse Width &lt; 300μs, Duty Cycle &lt;2%

**Thermal-Mechanical Specifications**

Parameters	11DQ..	Units	Conditions	
$T_J$ Max. Junction Temperature Range (*)	-40 to 150	°C		
$T_{stg}$ Max. Storage Temperature Range	-40 to 150	°C		
$R_{thJA}$ Max. Thermal Resistance Junction to Ambient	100	°C/W	DC operation Without cooling fin	
$R_{thJL}$ Typical Thermal Resistance Junction to Lead	81	°C/W	DC operation (See Fig. 4)	
wt Approximate Weight	0.33(0.012)	g(oz.)		
Case Style	DO-204AL(DO-41)			

(\*)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th}(j-a)}$  thermal runaway condition for a diode on its own heatsink

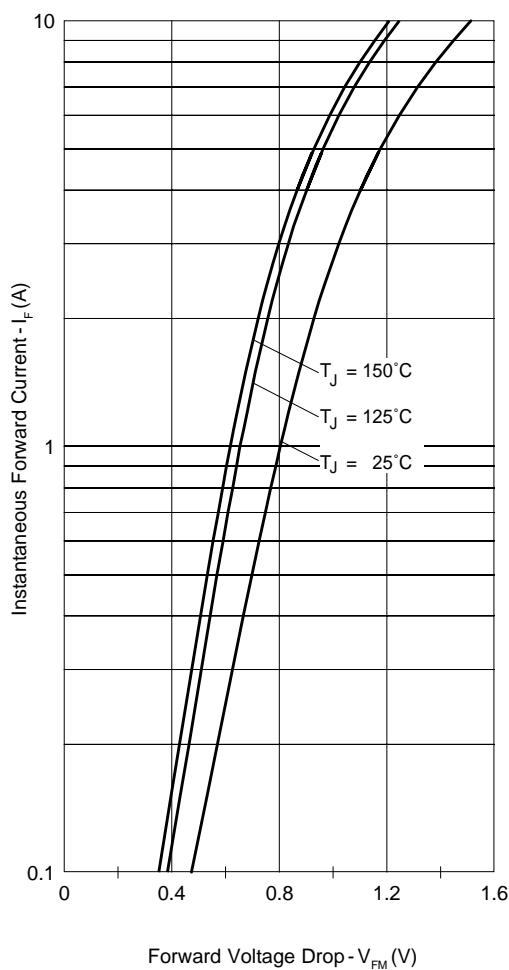


Fig. 1 - Max. Forward Voltage Drop Characteristics

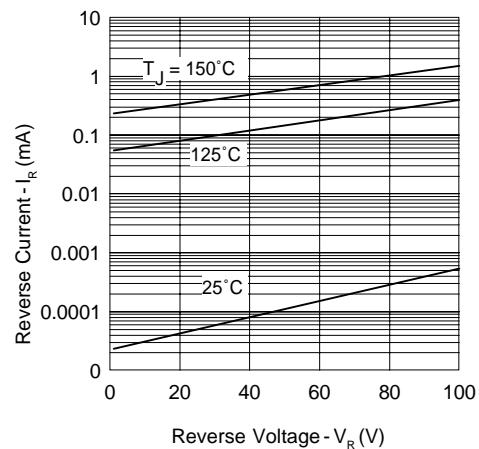


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

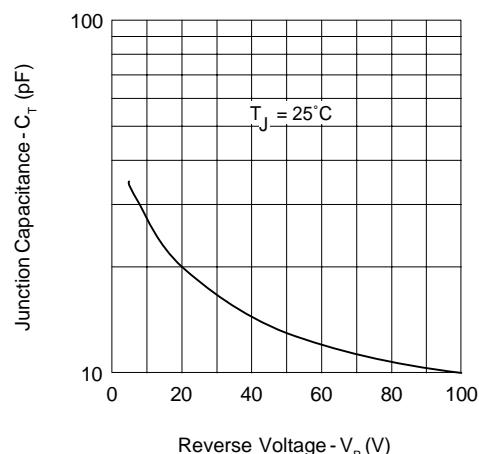
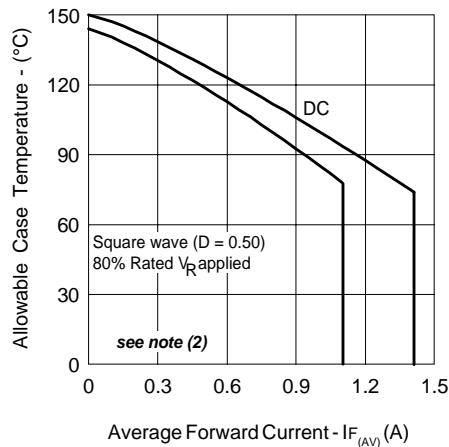
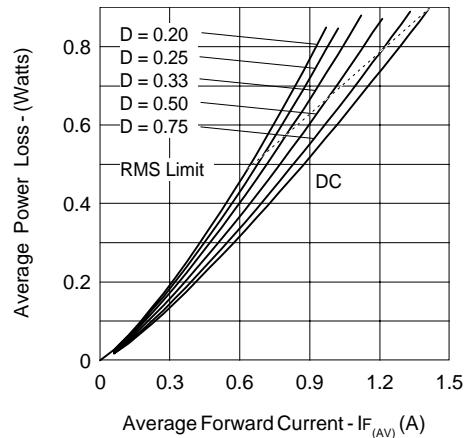


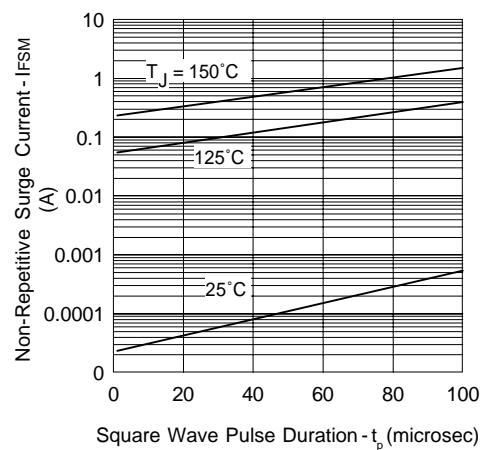
Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage



**Fig. 4 - Max. Allowable Case Temperature Vs. Average Forward Current**



**Fig. 5 - Forward Power Loss Characteristics**



**Fig. 6 - Max. Non-Repetitive Surge Current**

(2) Formula used:  $T_C = T_J - (P_d + P_{d,REV}) \times R_{thJC}$ ;  
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);  
 $P_{d,REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% \text{ rated } V_R$

Ordering Information Table

Device Code	11	D	Q	10	TR
	(1)	(2)	(3)	(4)	(5)
<b>1</b>	- 11 = 1.1A (Axial and small packages - Current is x10)				
<b>2</b>	- D = DO-41 package				
<b>3</b>	- Q = Schottky Q.. Series				
<b>4</b>	- 10 = Voltage Ratings				10 = 100V 09 = 90V
<b>5</b>	- TR = Tape & Reel package ( 5000 pcs) - = Box package (1000 pcs)				

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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